

KSC2753

Low Noise Amplifier for Vhf/uhf

- High Current Gain Bandwidth Product : f_T=5GHz
 NF=1.5dB, IS_{21e}I² = 16dB at f=500MHz
 NF=1.7dB, IS_{21e}I² = 10.5dB at f=1000MHz



NPN Epitaxial Silicon Transistor

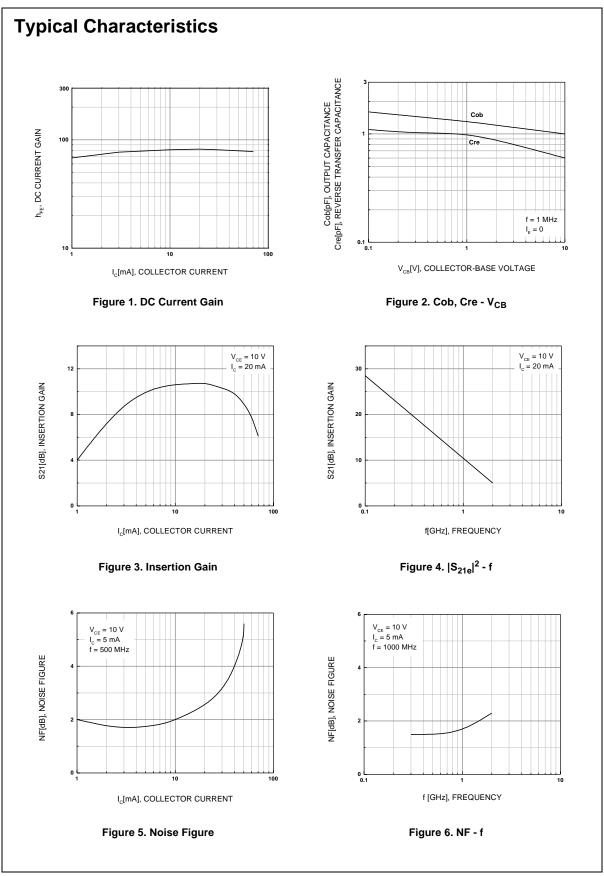
Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	17	V
V_{CEO}	Collector-Emitter Voltage	12	V
V_{EBO}	Emitter-Base Voltage	3	V
I _C	Collector Current	70	mA
I _B	Base Current	30	mA
P _C	Collector Dissipation	300	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V _{CB} =10V, I _E =0			1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB}=1V$, $I_{C}=0$			1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10, I _C =20mA	30		180	
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =20mA		5		GHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		1.1		pF
C _{RE}	Reverse Transfer Capacitance	V _{CB} =10V, I _E =0, f=1MHz		0.65		pF
IS _{21e} l ² (1)	Insertion Gain	V _{CE} =10V, I _C =20mA, f=500MHz		16		dB
IS _{21e} l ² (2)		V _{CE} =10V, I _C =20mA f=1000MHz		10.5		dB
NF(1)	Noise Figure	V _{CE} =10V, I _C =5mA, f=500MHz		1.5		dB
NF(2)		V_{CE} =10V, I_{C} =5mA, f=1000MHz		1.7		dB

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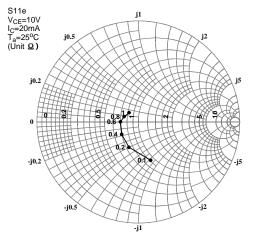


Figure 7. S11

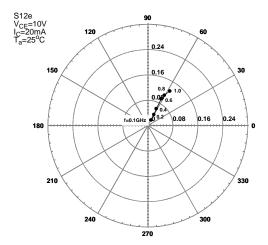


Figure 8. S12

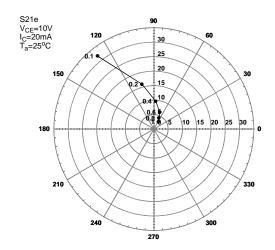


Figure 9. S21

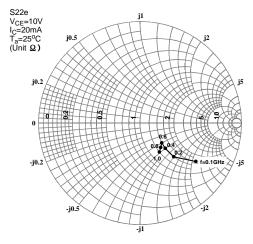


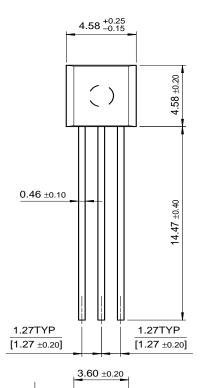
Figure 10. S22

Rev. A, February 2000

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Package Demensions

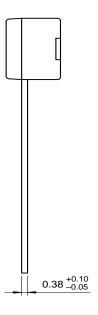
TO-92



(R2.29)

1.02 ±0.10 0.38 ^{+0.10} 0.38 −0.05





Rev. A, February 2000

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